Attv. Dkt. No. 023312-0109



Applicant: Takashi NAGASE et. al.

Title:

METHOD OF

MANUFACTURING NANO-GAP

ELECTRODE

Appl. No.: 10/662,886

Filing Date: 09/16/2003

Examiner: Unassigned

Art Unit: Unassigned

INFORMATION DISCLOSURE STATEMENT **UNDER 37 CFR §1.56**

Commissioner for Patents PO Box 1450 Alexandria, Virginia 22313-1450

Sir

Submitted herewith on Form PTO/SB/08 is a listing of documents known to Applicants in order to comply with Applicants' duty of disclosure pursuant to 37 CFR §1.56. A copy of each listed document is being submitted to comply with the provisions of 37 CFR §1.97 and §1.98.

The submission of any document herewith, which is not a statutory bar, is not intended as an admission that such document constitutes prior art against the claims of the present application or that such document is considered material to patentability as defined in 37 CFR §1.56(b). Applicants do not waive any rights to take any action which would be appropriate to antedate or otherwise remove as a competent reference any document which is determined to be a prima facie art reference against the claims of the present application.

Atty, Dkt. No. 023312-0109

TIMING OF THE DISCLOSURE

The listed documents are being submitted in compliance with 37 CFR §1.97(b), before the mailing date of the first Office Action on the merits.

RELEVANCE OF EACH DOCUMENT

All of the documents are in English.

Applicants respectfully request that any listed document be considered by the Examiner and be made of record in the present application and that an initialed copy of Form PTO/SB/08 be returned in accordance with MPEP §609.

The Commissioner is hereby authorized to charge any additional fees which may be required regarding this application under 37 CFR §§ 1.16-1.17, or credit any overpayment, to Deposit Account No. 19-0741. Should no proper payment be enclosed herewith, as by a check being in the wrong amount, unsigned, post-dated, otherwise improper or informal or even entirely missing, the Commissioner is authorized to charge the unpaid amount to Deposit Account No. 19-0741.

Respectfully submitted,

FOLEY & LARDNER

Customer Number: 22428

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MODIFIED PTO/SB/08 (08-00)

Approved for use through 10/31/2002. OMB 0851-0031 U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE red to respond to a collection of information unless it contains a valid OMB control

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Substitute for form 1449B/PTO THALL Complete if Known 10/662,886 INFORMATION DISCLOSURE **Application Number** 09/16/2003 STATEMENT BY APPLICANT Filing Date Takashi NAGASE First Named Inventor Date Submitted: 11/6/03 Group Art Unit Unassigned (use as many sheets as necessary) **Examiner Name** Unassigned of 1 1 Attorney Docket Number 023312-0109 Sheet 1

				U.S. PATENT DOCUMENTS		
Examiner Initials*		U.S. Patent Document		No. of Detector or Applicant of	Date of Publication of	Pages, Columns, Lines, Where Relevant
	Cite No. ¹	Number	Kind Code ² (if known)	Name of Patentee or Applicant of Cited Document	Cited Document MM-DD-YYYY	Passages or Relevant Figures Appear
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	FOREIGN PATENT DOCUMENTS									
Examiner Initials*	Cite No.1	Foreign Patent D Office ³ Number ⁴		Nocument Kind Code ⁵ (if known)	Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appeer	T ⁶		

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.1	Include name of the author (in CAP11AL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	Т		
	A4	R.L. Kubena, et al, A Low Magnification Focused Ion Beam System with 8 nm spot size", J. Vac. Sci. Technol. B9, 3079-3083 (1991)	Y		
	A5	S. Matsui, et al, High Resolution Focused Ion Beam Lithography, J. Vac. Sci. Technol. B9, 2622-2632 (1991)	Y		
	A6	M.A. Reed, Molecular-Scale Electronics, Proc. IEEE, 87, 652-658 (1999)	Y		
	A7	A. Aviram, et al, Molecular Electronics II, New York Academy of Sciences, New York (2002) – Table of Contents	Y		
	A8	Y. Wada, et al., Prospects and Problems of Single Molecule Information Devices, Jpn. J. Appl. Phys. Part 1, 39, 3835-3849 (2000)	Y		

Examiner	Date
Signature	Considered

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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